Low-ohmic single-pole double-throw analog switch

Rev. 7.1 — 15 November 2016

Product data sheet

1. General description

The NX3L1G53 is a low-ohmic single-pole double-throw analog switch suitable for use as an analog or digital 2:1 multiplexer/demultiplexer. It has a digital select input (S), two independent inputs/outputs (Y0 and Y1), a common input/output (Z) and an active LOW enable input (\overline{E}). When pin \overline{E} is HIGH, the switch is turned off. Schmitt trigger action at the digital inputs makes the circuit tolerant to slower input rise and fall times.

The NX3L1G53 allows signals with amplitude up to V_{CC} to be transmitted from Z to Y0 or Y1; or from Y0 or Y1 to Z. Its low ON resistance (0.5 Ω) and flatness (0.13 Ω) ensures minimal attenuation and distortion of transmitted signals.

2. Features and benefits

- Wide supply voltage range from 1.4 V to 4.3 V
- Very low ON resistance (peak):
 - 1.6 Ω (typical) at V_{CC} = 1.4 V
 - 1.0 Ω (typical) at V_{CC} = 1.65 V
 - 0.55 Ω (typical) at V_{CC} = 2.3 V
 - 0.50 Ω (typical) at V_{CC} = 2.7 V
 - 0.50 Ω (typical) at V_{CC} = 4.3 V
- Break-before-make switching
- High noise immunity
- ESD protection:
 - HBM JESD22-A114F Class 3A exceeds 7500 V
 - MM JESD22-A115-A exceeds 200 V
 - CDM AEC-Q100-011 revision B exceeds 1000 V
 - IEC61000-4-2 contact discharge exceeds 8000 V for switch ports
- CMOS low-power consumption
- Latch-up performance exceeds 100 mA per JESD 78 Class II Level A
- Direct interface with TTL levels at 3.0 V
- Control input accepts voltages above supply voltage
- High current handling capability (350 mA continuous current under 3.3 V supply)
- Specified from –40 °C to +85 °C and from –40 °C to +125 °C



3. Applications

- Cell phone
- PDA
- Portable media player

4. Ordering information

Table 1. Ordering information

| Type number | Package | Package | | | | | | | |
|-------------|-------------------|---------|---|----------|--|--|--|--|--|
| | Temperature range | Name | Description | Version | | | | | |
| NX3L1G53GT | –40 °C to +125 °C | XSON8 | plastic extremely thin small outline package; no leads; 8 terminals; body 1 \times 1.95 \times 0.5 mm | SOT833-1 | | | | | |
| NX3L1G53GD | –40 °C to +125 °C | XSON8 | plastic extremely thin small outline package; no leads; 8 terminals; body $3 \times 2 \times 0.5$ mm | SOT996-2 | | | | | |
| NX3L1G53GM | –40 °C to +125 °C | XQFN8 | plastic, extremely thin quad flat package; no leads; 8 terminals; body $1.6 \times 1.6 \times 0.5$ mm | SOT902-2 | | | | | |

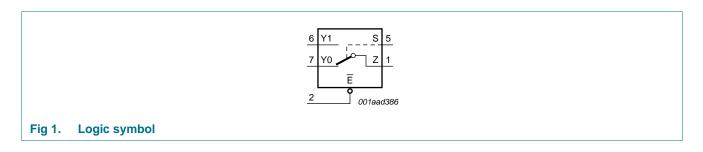
5. Marking

Table 2. Marking codes^[1]

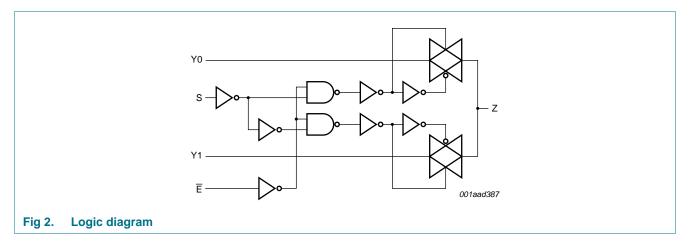
| Type number | Marking code |
|-------------|--------------|
| NX3L1G53GT | D53 |
| NX3L1G53GD | D53 |
| NX3L1G53GM | D53 |

[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

6. Functional diagram

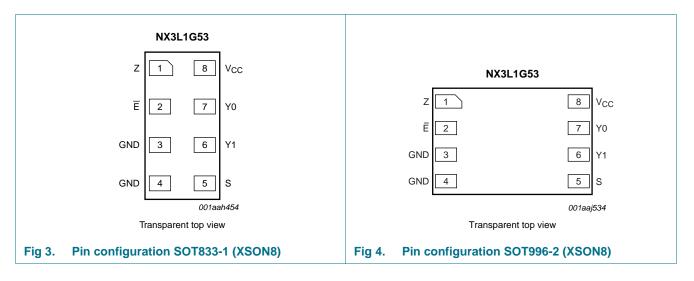


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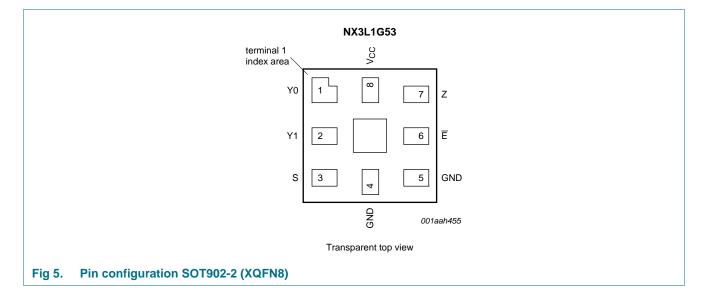
7. Pinning information

7.1 Pinning



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7.2 Pin description

| Table 3. | Pin description | | |
|-----------------|-----------------------|----------|-----------------------------|
| Symbol | Pin | | Description |
| | SOT833-1 and SOT996-2 | SOT902-2 | |
| Z | 1 | 7 | common output or input |
| E | 2 | 6 | enable input (active LOW) |
| GND | 3 | 5 | ground (0 V) |
| GND | 4 | 4 | ground (0 V) |
| S | 5 | 3 | select input |
| Y1 | 6 | 2 | independent input or output |
| Y0 | 7 | 1 | independent input or output |
| V _{CC} | 8 | 8 | supply voltage |
| | | | |

8. Functional description

Table 4.Function table

| Input | Channel | |
|-------|---------|--------------------|
| S | Ē | |
| L | L | Y0 to Z or Z to Y0 |
| Н | L | Y1 to Z or Z to Y1 |
| Х | Н | switch off |

[1] H = HIGH voltage level; L = LOW voltage level; X = don't care.

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9. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|------------------|-------------------------|---|-----------------|-----------------------|------|
| V _{CC} | supply voltage | | -0.5 | +4.6 | V |
| VI | input voltage | select input S and enable input \overline{E} | <u>[1]</u> –0.5 | +4.6 | V |
| V _{SW} | switch voltage | | [2] _0.5 | V _{CC} + 0.5 | V |
| I _{IK} | input clamping current | $V_{l} < -0.5 V$ | -50 | - | mA |
| I _{SK} | switch clamping current | $V_{\rm I} < -0.5$ V or $V_{\rm I} > V_{\rm CC}$ + 0.5 V | - | ±50 | mA |
| I _{SW} | switch current | V_{SW} > -0.5 V or V_{SW} < V_{CC} + 0.5 V; source or sink current | - | ±350 | mA |
| | | V _{SW} > -0.5 V or V _{SW} < V _{CC} + 0.5 V; pulsed at 1 ms duration, < 10 % duty cycle; peak current | - | ±500 | mA |
| T _{stg} | storage temperature | | -65 | +150 | °C |
| P _{tot} | total power dissipation | $T_{amb} = -40 \text{ °C to } +125 \text{ °C}$ | [3] _ | 250 | mW |

[1] The minimum input voltage rating may be exceeded if the input current rating is observed.

[2] The minimum and maximum switch voltage ratings may be exceeded if the switch clamping current rating is observed but may not exceed 4.6 V.

[3] For XSON8 and XQFN8 packages: above 118 °C the value of P_{tot} derates linearly with 7.8 mW/K.

10. Recommended operating conditions

Table 6. Recommended operating conditions

| Symbol | Parameter | Conditions | Min | Max | Unit |
|-----------------------|-------------------------------------|--|--------------|-----------------|------|
| V _{CC} | supply voltage | | 1.4 | 4.3 | V |
| VI | input voltage | select input S and enable input \overline{E} | 0 | 4.3 | V |
| V _{SW} | switch voltage | | <u>[1]</u> 0 | V _{CC} | V |
| T _{amb} | ambient temperature | | -40 | +125 | °C |
| $\Delta t / \Delta V$ | input transition rise and fall rate | V_{CC} = 1.4 V to 4.3 V | [2] _ | 200 | ns/V |

[1] To avoid sinking GND current from terminal Z when switch current flows in terminal Yn, the voltage drop across the bidirectional switch must not exceed 0.4 V. If the switch current flows into terminal Z, no GND current will flow from terminal Yn. In this case, there is no limit for the voltage drop across the switch.

[2] Applies to control signals.

11. Static characteristics

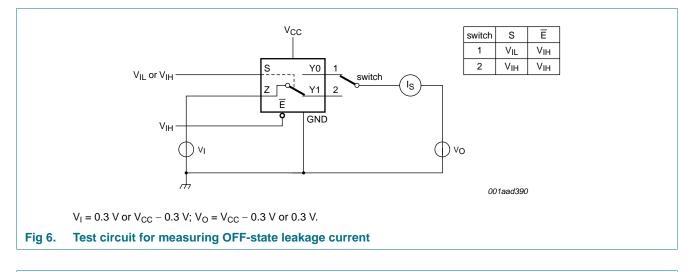
Table 7. Static characteristics

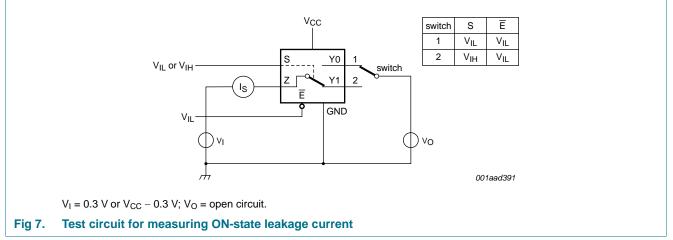
At recommended operating conditions; voltages are referenced to GND (ground 0 V).

| Symbol | Parameter | Conditions | | 25 °C | | | –40 °C to +125 °C | | |
|--------------------|--------------------------|--|--------------|-------|--------------|--------------|-------------------|-----------------|----|
| | | | Min | Тур | Max | Min | Max (85 °C) | Max (125 °C) | |
| V _{IH} | HIGH-level | $V_{CC} = 1.4 \text{ V}$ to 1.95 V | $0.65V_{CC}$ | - | - | $0.65V_{CC}$ | - | - | V |
| | input voltage | V_{CC} = 2.3 V to 2.7 V | 1.7 | - | - | 1.7 | - | - | V |
| | | V_{CC} = 2.7 V to 3.6 V | 2.0 | - | - | 2.0 | - | - | V |
| | | $V_{CC} = 3.6 \text{ V to } 4.3 \text{ V}$ | $0.7V_{CC}$ | - | - | $0.7V_{CC}$ | - | - | V |
| V _{IL} | LOW-level | V_{CC} = 1.4 V to 1.95 V | - | - | $0.35V_{CC}$ | - | $0.35V_{CC}$ | $0.35V_{CC}$ | V |
| | input voltage | V_{CC} = 2.3 V to 2.7 V | - | - | 0.7 | - | 0.7 | 0.7 | V |
| | | $V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$ | - | - | 0.8 | - | 0.8 | 0.8 | V |
| | | $V_{CC} = 3.6 \text{ V to } 4.3 \text{ V}$ | - | - | $0.3V_{CC}$ | - | $0.3V_{CC}$ | $0.3V_{CC}$ | V |
| II | input leakage current | select input S and enable input \overline{E} ; V _I = GND to 4.3 V; V _{CC} = 1.4 V to 4.3 V | - | - | - | - | ±0.5 | ±1 | μΑ |
| $I_{S(OFF)}$ | OFF-state leakage | Y0 and Y1 port; see <u>Figure 6</u> | | | | | | | |
| | current | V_{CC} = 1.4 V to 3.6 V | - | - | ±5 | - | ±50 | ±500 | nA |
| | | V_{CC} = 3.6 V to 4.3 V | - | - | ±10 | - | ±50 | ±500 | nA |
| I _{S(ON)} | ON-state | Z port; see Figure 7 | | | | | | | |
| | leakage current | V_{CC} = 1.4 V to 3.6 V | - | - | ±5 | - | ±50 | ±500 | nA |
| | current | V_{CC} = 3.6 V to 4.3 V | - | - | ±10 | - | ±50 | ±500 | nA |
| I _{CC} | supply current | $V_I = V_{CC}$ or GND; $V_{SW} = GND$ or V_{CC} | | | | | | | |
| | | $V_{CC} = 3.6 V$ | - | - | 100 | - | 690 | 6000 | nA |
| | | $V_{CC} = 4.3 V$ | - | - | 150 | - | 800 | 7000 | nA |
| CI | input capacitance | | - | 1.0 | - | - | - | - | pF |
| $C_{S(OFF)}$ | OFF-state capacitance | | - | 35 | - | - | - | - | pF |
| C _{S(ON)} | ON-state capacitance | | - | 130 | - | - | - | - | pF |

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11.1 Test circuits





11.2 ON resistance

Table 8. ON resistance

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for graphs see Figure 9 to Figure 15.

| Symbol | Parameter | Conditions | -40 | °C to +8 | 5 °C | –40 °C to | • +125 °C | Unit |
|-----------------------|---|--|-----|----------------------|-------|-----------|-----------|------|
| | | | Min | Typ <mark>[1]</mark> | Max | Min | Мах | |
| R _{ON(peak)} | ON resistance (peak) | $V_I = GND$ to V_{CC} ; $I_{SW} = 100$ mA; see Figure 8 | | | | | | |
| | | $V_{CC} = 1.4 V$ | - | 1.6 | 3.7 | - | 4.1 | Ω |
| | | V _{CC} = 1.65 V | - | 1.0 | 1.6 | - | 1.7 | Ω |
| | | $V_{CC} = 2.3 V$ | - | 0.55 | 0.8 | - | 0.9 | Ω |
| | | $V_{CC} = 2.7 V$ | - | 0.5 | 0.75 | - | 0.9 | Ω |
| | | $V_{CC} = 4.3 V$ | - | 0.5 | 0.75 | - | 0.9 | Ω |
| ΔR_{ON} | ON resistance mismatch between channels | $V_{I} = \text{GND to } V_{\text{CC}}; \qquad [2] \\ I_{\text{SW}} = 100 \text{ mA}$ | | | | | | |
| | | $V_{CC} = 1.4 V$ | - | 0.04 | 0.3 | - | 0.3 | Ω |
| | | V _{CC} = 1.65 V | - | 0.04 | 0.2 | - | 0.3 | Ω |
| | | $V_{CC} = 2.3 V$ | - | 0.02 | 0.08 | - | 0.1 | Ω |
| | | $V_{CC} = 2.7 V$ | - | 0.02 | 0.075 | - | 0.1 | Ω |
| | | $V_{CC} = 4.3 V$ | - | 0.02 | 0.075 | - | 0.1 | Ω |
| R _{ON(flat)} | ON resistance (flatness) | $V_I = GND$ to V_{CC} ; [3] $I_{SW} = 100 \text{ mA}$ | | | | | | |
| | | $V_{CC} = 1.4 V$ | - | 1.0 | 3.3 | - | 3.6 | Ω |
| | | V _{CC} = 1.65 V | - | 0.5 | 1.2 | - | 1.3 | Ω |
| | | $V_{CC} = 2.3 V$ | - | 0.15 | 0.3 | - | 0.35 | Ω |
| | | $V_{CC} = 2.7 V$ | - | 0.13 | 0.3 | - | 0.35 | Ω |
| | | $V_{CC} = 4.3 V$ | - | 0.2 | 0.4 | - | 0.45 | Ω |

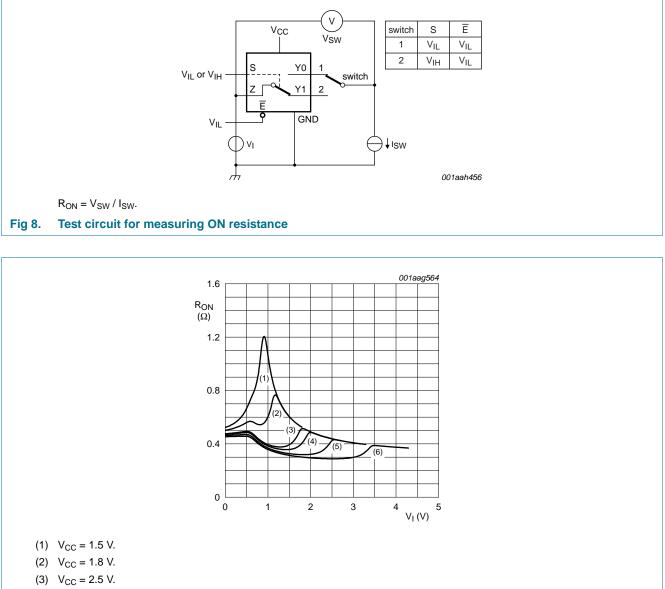
[1] Typical values are measured at $T_{amb} = 25 \ ^{\circ}C$.

[2] Measured at identical V_{CC}, temperature and input voltage.

[3] Flatness is defined as the difference between the maximum and minimum value of ON resistance measured at identical V_{CC} and temperature.

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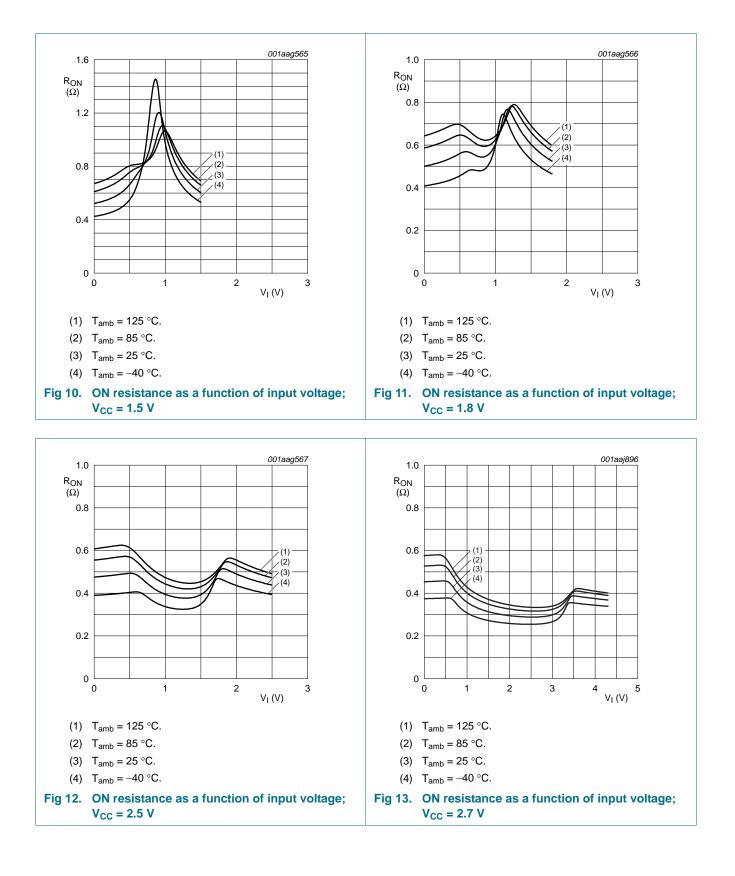
11.3 ON resistance test circuit and waveforms



- (4) $V_{CC} = 2.7 V.$
- (5) $V_{CC} = 3.3 V.$ (6) $V_{CC} = 4.3$ V.
 - Measured at $T_{amb} = 25 \ ^{\circ}C$.
- Fig 9. ON resistance as a function of input voltage

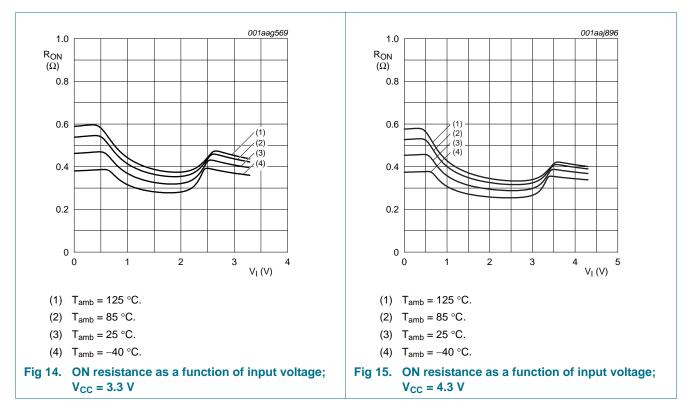
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12. Dynamic characteristics

Table 9. Dynamic characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for load circuit see Figure 18.

| Symbol | Parameter | Conditions | | 25 °C | | -40 | °C to +12 | 5 °C | Unit |
|------------------|--------------|--|-----|----------------------|-----|------------|----------------|-----------------|------|
| | | | Min | Typ <mark>[1]</mark> | Max | Min | Max (85 °C) | Max (125 °C) | |
| t _{en} | enable time | S or E to Z or Yn; see <u>Figure 16</u> | | | | | | | |
| | | V_{CC} = 1.4 V to 1.6 V | - | 28 | 42 | - | 45 | 50 | ns |
| | | V _{CC} = 1.65 V to 1.95 V | - | 23 | 34 | - | 37 | 41 | ns |
| | | V_{CC} = 2.3 V to 2.7 V | - | 17 | 27 | - | 29 | 31 | ns |
| | | V_{CC} = 2.7 V to 3.6 V | - | 15 | 24 | - | 26 | 28 | ns |
| | | V_{CC} = 3.6 V to 4.3 V | - | 15 | 24 | - | 26 | 28 | ns |
| t _{dis} | disable time | S or Ē to Z or Yn; see <u>Figure 16</u> | | | | | | | |
| | | V_{CC} = 1.4 V to 1.6 V | - | 10 | 19 | - | 21 | 23 | ns |
| | | V_{CC} = 1.65 V to 1.95 V | - | 7 | 14 | - | 16 | 17 | ns |
| | | V_{CC} = 2.3 V to 2.7 V | - | 5 | 9 | - | 10 | 11 | ns |
| | | V_{CC} = 2.7 V to 3.6 V | - | 4 | 8 | - | 9 | 9 | ns |
| | | V_{CC} = 2.7 V to 4.3 V | - | 4 | 8 | - | 9 | 9 | ns |

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| Symbol | Parameter Conditions 25 °C | | –40 °C to +125 °C | | | Unit | | | | |
|------------------|----------------------------|--|-------------------|-----|----------------------|------|-----|----------------|-----------------|----|
| | | | | Min | Typ <mark>[1]</mark> | Мах | Min | Max (85 °C) | Max (125 °C) | |
| t _{b-m} | break-before-make | see Figure 17 | [2] | | | | | | | |
| time | time | V_{CC} = 1.4 V to 1.6 V | | - | 19 | - | 9 | - | - | ns |
| | | V_{CC} = 1.65 V to 1.95 V | | - | 17 | - | 7 | - | - | ns |
| | | V_{CC} = 2.3 V to 2.7 V | | - | 13 | - | 5 | - | - | ns |
| | | $V_{CC} = 2.7 \text{ V} \text{ to } 3.6 \text{ V}$ | | - | 10 | - | 3 | - | - | ns |
| | | V_{CC} = 2.7 V to 4.3 V | | - | 10 | - | 2 | - | - | ns |

Table 9. Dynamic characteristics ... continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for load circuit see Figure 18.

[1] Typical values are measured at T_{amb} = 25 °C and V_{CC} = 1.5 V, 1.8 V, 2.5 V, 3.3 V and 4.3 V respectively.

[2] Break-before-make guaranteed by design.

12.1 Waveform and test circuits

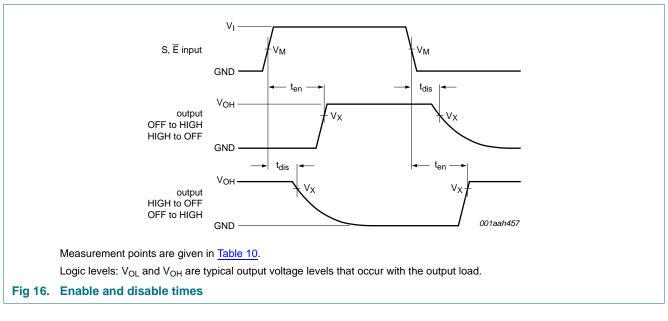
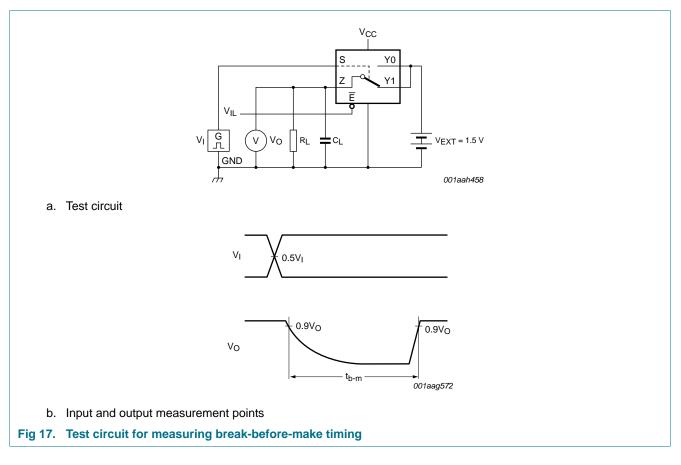


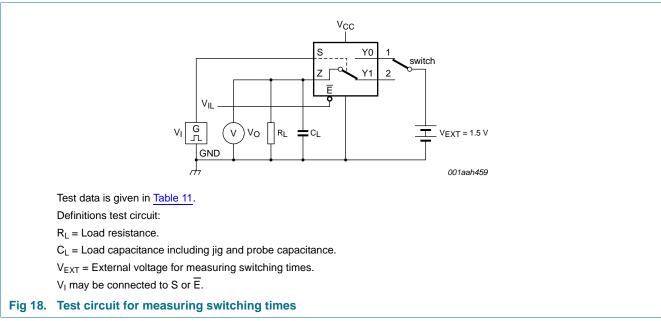
Table 10. Measurement points

| Supply voltage | Input | Output |
|-----------------|--------------------|--------------------|
| V _{cc} | V _M | V _X |
| 1.4 V to 4.3 V | 0.5V _{CC} | 0.9V _{OH} |

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Table 11.Test data

| Supply voltage | Input | | Load | |
|-----------------|--|----------|-------|------|
| V _{cc} | V _I t _r , t _f C | | CL | RL |
| 1.4 V to 4.3 V | V _{CC} | ≤ 2.5 ns | 35 pF | 50 Ω |

12.2 Additional dynamic characteristics

Table 12. Additional dynamic characteristics

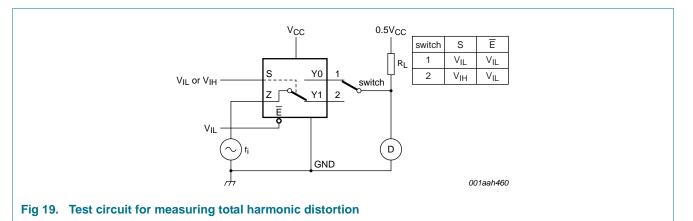
At recommended operating conditions; voltages are referenced to GND (ground = 0 V); $V_I = GND$ or V_{CC} (unless otherwise specified); $t_r = t_f \le 2.5$ ns; $T_{amb} = 25$ °C.

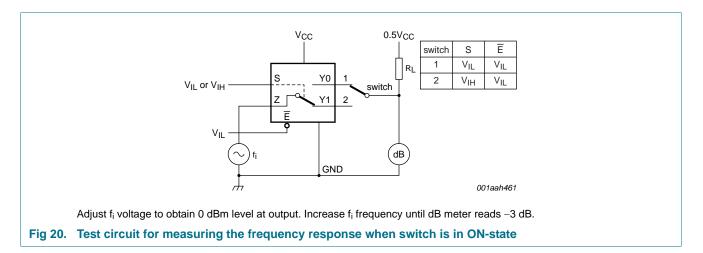
| Symbol | Parameter | Conditions | Min | Тур | Мах | Unit |
|-----------------------|------------------------------|---|------------|------|-----|------|
| THD | total harmonic distortion | $f_i = 20 \text{ Hz to } 20 \text{ kHz}; \text{ R}_L = 32 \Omega; \text{ see } \frac{\text{Figure } 19}{1000 \text{ sec } 19}$ | <u>[1]</u> | | | |
| | | V _{CC} = 1.4 V; V _I = 1 V (p-p) | - | 0.15 | - | % |
| | | V _{CC} = 1.65 V; V _I = 1.2 V (p-p) | - | 0.10 | - | % |
| | | V _{CC} = 2.3 V; V _I = 1.5 V (p-p) | - | 0.02 | - | % |
| | | V _{CC} = 2.7 V; V _I = 2 V (p-p) | - | 0.02 | - | % |
| | | V _{CC} = 4.3 V; V _I = 2 V (p-p) | - | 0.02 | - | % |
| f _(-3dB) | –3 dB frequency response | $R_L = 50 \Omega$; see <u>Figure 20</u> | <u>[1]</u> | | | |
| | | $V_{CC} = 1.4 \text{ V to } 4.3 \text{ V}$ | - | 60 | - | MHz |
| α_{iso} | isolation (OFF-state) | $f_i = 100 \text{ kHz}; R_L = 50 \Omega; \text{ see } \frac{\text{Figure 21}}{100 \text{ kHz}}$ | <u>[1]</u> | | | |
| | | $V_{CC} = 1.4 \text{ V to } 4.3 \text{ V}$ | - | -90 | - | dB |
| V _{ct} | crosstalk voltage | between digital inputs and switch; $f_i = 1 \text{ MHz}$; $C_L = 50 \text{ pF}$; $R_L = 50 \Omega$; see Figure 22 | | | | |
| | | $V_{CC} = 1.4 \text{ V to } 3.6 \text{ V}$ | - | 0.2 | - | V |
| | | $V_{CC} = 3.6 \text{ V to } 4.3 \text{ V}$ | - | 0.3 | - | V |
| Xtalk | crosstalk | between switches; $f_i = 100 \text{ kHz}$; $R_L = 50 \Omega$; see <u>Figure 23</u> | [1] | | | |
| | | $V_{CC} = 1.4 \text{ V to } 4.3 \text{ V}$ | - | -90 | - | dB |
| Q _{inj} | charge injection | $f_i = 1 \text{ MHz}; C_L = 0.1 \text{ nF}; R_L = 1 \text{ M}\Omega; V_{gen} = 0 \text{ V}; R_{gen} = 0 \Omega;$ see <u>Figure 24</u> | | | | |
| | | $V_{CC} = 1.5 V$ | - | 3 | - | рС |
| | | V _{CC} = 1.8 V | - | 4 | - | рС |
| | | $V_{CC} = 2.5 V$ | - | 6 | - | рС |
| | | $V_{CC} = 3.3 V$ | - | 9 | - | рС |
| | | $V_{CC} = 4.3 V$ | - | 15 | - | рС |

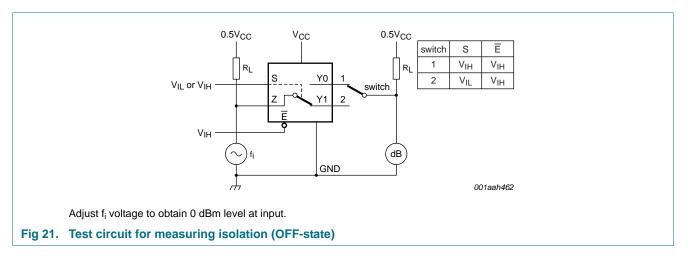
[1] f_i is biased at 0.5V_{CC}.

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12.3 Test circuits



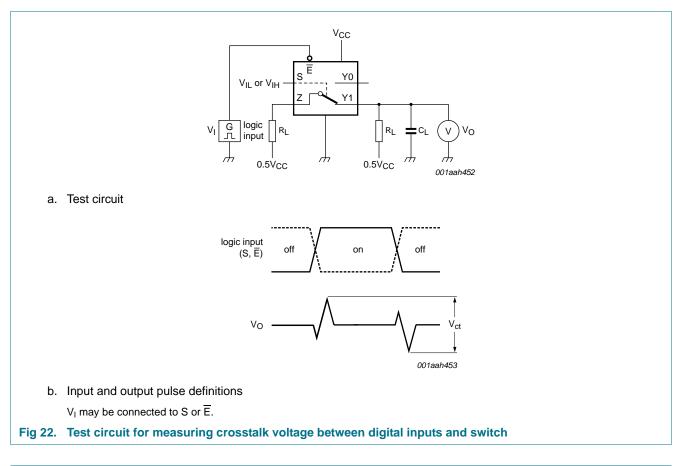


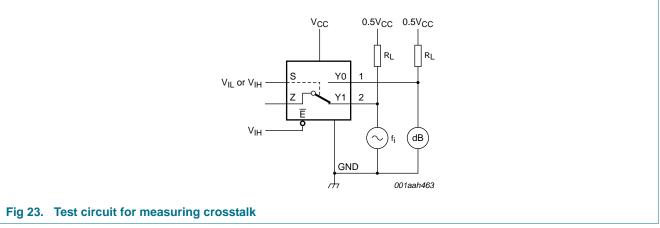


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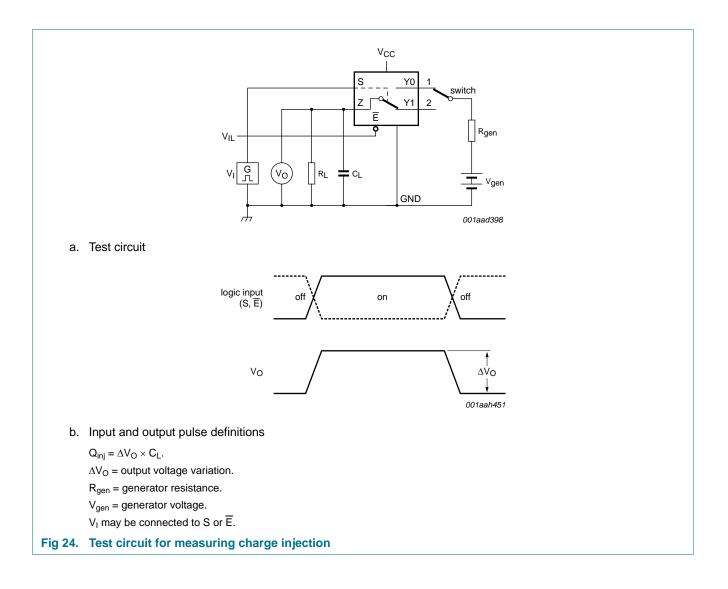
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13. Package outline

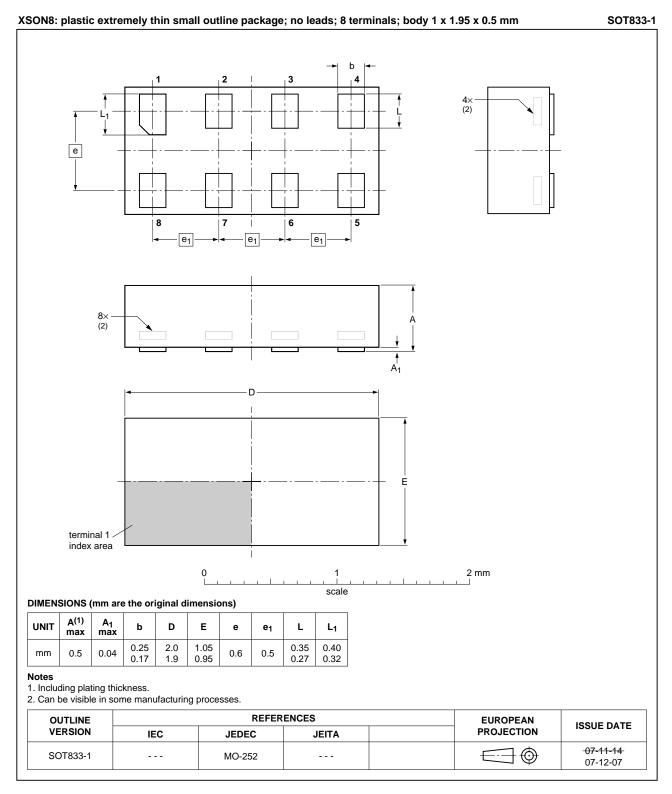
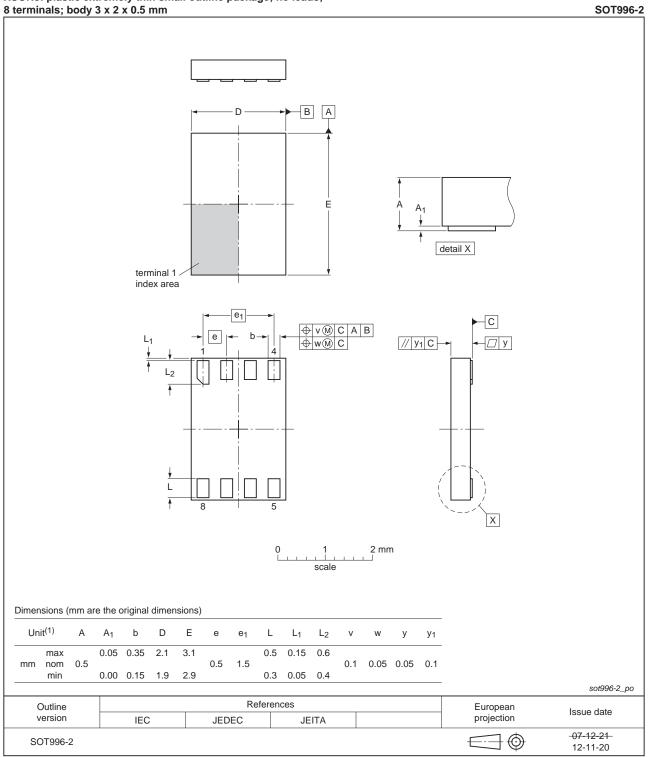


Fig 25. Package outline SOT833-1 (XSON8)

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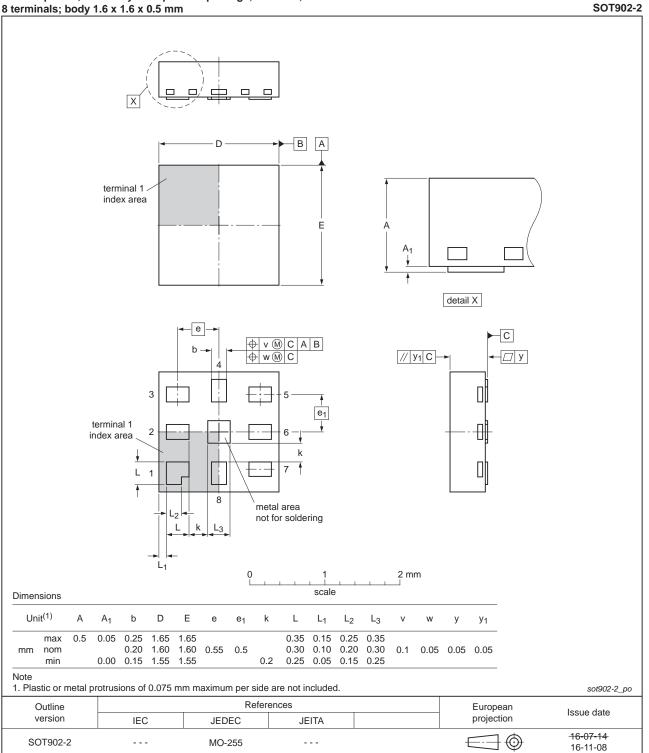
XSON8: plastic extremely thin small outline package; no leads;

Fig 26. Package outline SOT996-2 (XSON8)

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Low-ohmic single-pole double-throw analog switch



XQFN8: plastic, extremely thin quad flat package; no leads; 8 terminals; body 1.6 x 1.6 x 0.5 mm

Fig 27. Package outline SOT902-2 (XQFN8)

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14. Abbreviations

| Table 13. | Abbreviations | | |
|-----------|---|--|--|
| Acronym | Description | | |
| CDM | Charged Device Model | | |
| CMOS | Complementary Metal Oxide Semiconductor | | |
| ESD | ElectroStatic Discharge | | |
| HBM | Human Body Model | | |
| MM | Machine Model | | |
| TTL | Transistor-Transistor Logic | | |

15. Revision history

| Table 14. Revision | history | | | |
|--------------------|-----------------------------------|----------------------------|-----------------------|--------------|
| Document ID | Release date | Data sheet status | Change notice | Supersedes |
| NX3L1G53 v.7.1 | 20161115 | Product data sheet | - | NX3L1G53 v.7 |
| Modifications: | Updated Fig | gure 27 "Package outline S | OT902-2 (XQFN8)" | |
| NX3L1G53 v.7 | 20130208 | Product data sheet | - | NX3L1G53 v.6 |
| Modifications: | For type null | mber NX3L1G53GD XSON | 8U has changed to XSO | N8 |
| NX3L1G53 v.6 | 20120613 | Product data sheet | - | NX3L1G53 v.5 |
| NX3L1G53 v.5 | 20111109 | Product data sheet | - | NX3L1G53 v.4 |
| NX3L1G53 v.4 | 20100127 | Product data sheet | - | NX3L1G53 v.3 |
| NX3L1G53 v.3 | 20090417 | Product data sheet | - | NX3L1G53 v.2 |
| NX3L1G53 v.2 | 20080718 | Product data sheet | - | NX3L1G53 v.1 |
| NX3L1G53 v.1 | 20080408 | Product data sheet | - | - |
| | | | | |

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|--------------------------------|-------------------------------|---|
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| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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